Excellent Integrated System Limited

Stocking Distributor

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Vishay Semiconductor/Diodes Division
VS-VSKH105/04

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite
Datasheet of VS-VSKH105/04 - MODULE DIODE 400V 105A ADD-A-PAK
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

VS-VSKT105.., VS-VSKH105.., VS-VSKL105.., VS-VSKN105.. Series

ADD-A-PAK Generation VII Power Modules Thyristor/Diode and Thyristor/Thyristor, 105 A

ADD-A-PAK

FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

PRODUCT SUMMARY	
$I_{T(AV)}$ or $I_{F(AV)}$	105 A
Type	Modules - Thyristor, Standard

MECHANICAL DESCRIPTION

The ADD-A-PAK Generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{T(AV)}$ or $I_{F(AV)}$	85 °C	105	A
$I_{O(RMS)}$	As AC switch	235	
I_{TSM}, I_{FSM}	50 Hz	2000	
	60 Hz	2094	
I^2t	50 Hz	20	kA^2s
	60 Hz	18.26	
$I^2\sqrt{t}$		200	$kA^2\sqrt{s}$
V_{RRM}	Range	400 to 1600	V
T_{Stg}		-40 to 130	°C
T_J		-40 to 130	

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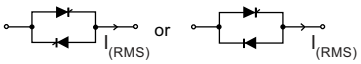
ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V_{DRM}, MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I_{RRM}, I_{DRM} AT 130 °C mA
VS-VSK.105	04	400	500	400	20
	06	600	700	600	
	08	800	900	800	
	10	1000	1100	1000	
	12	1200	1300	1200	
	14	1400	1500	1400	
	16	1600	1700	1600	

ON-STATE CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current (thyristors)	$I_{T(AV)}$	180° conduction, half sine wave, T_C = 85 °C			105	A
Maximum average forward current (diodes)	$I_{F(AV)}$					
Maximum continuous RMS on-state current, as AC switch	$I_{O(RMS)}$				235	
Maximum peak, one-cycle non-repetitive on-state or forward current	I_{TSM} or I_{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T_J = T_J maximum	2000	
		t = 8.3 ms			2094	
		t = 10 ms	100 % V_{RRM} reapplied		1682	
		t = 8.3 ms			1760	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied	Initial T_J = T_J maximum	20	kA^2s
		t = 8.3 ms			18.26	
		t = 10 ms	100 % V_{RRM} reapplied		14.14	
		t = 8.3 ms			12.91	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$ (1)	t = 0.1 ms to 10 ms, no voltage reapplied T_J = T_J maximum			200	$kA^2\sqrt{s}$
Maximum value or threshold voltage	$V_{T(TO)}$ (2)	Low level (3)	T_J = T_J maximum		0.98	V
		High level (4)			1.12	
Maximum value of on-state slope resistance	r_t (2)	Low level (3)	T_J = T_J maximum		2.7	mΩ
		High level (4)			2.34	
Maximum peak on-state or forward voltage	V_{TM}	I_{TM} = π x $I_{T(AV)}$	T_J = 25 °C		1.8	V
	V_{FM}	I_{FM} = π x $I_{F(AV)}$				
Maximum non-repetitive rate of rise of turned on current	dI/dt	T_J = 25 °C, from 0.67 V_{DRM}, I_{TM} = π x $I_{T(AV)}$, I_g = 500 mA, t_r < 0.5 µs, t_p > 6 µs			150	A/µs
Maximum holding current	I_H	T_J = 25 °C, anode supply = 6 V, resistive load, gate open circuit			250	mA
Maximum latching current	I_L	T_J = 25 °C, anode supply = 6 V, resistive load			400	

Notes

(1) I^2t for time t_x = $I^2\sqrt{t}$ x $\sqrt{t_x}$

(2) Average power = $V_{T(TO)}$ x $I_{T(AV)}$ + r_t x $(I_{T(RMS)})^2$

(3) 16.7 % x π x I_{AV} < I < π x I_{AV}

(4) I > π x I_{AV}

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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P_{GM}			12	W
Maximum average gate power	$P_{G(AV)}$			3	
Maximum peak gate current	I_{GM}			3	A
Maximum peak negative gate voltage	- V_{GM}			10	V
Maximum gate voltage required to trigger	V_{GT}	T_J = -40 °C	Anode supply = 6 V resistive load	4.0	
		T_J = 25 °C		2.5	
		T_J = 125 °C		1.7	
Maximum gate current required to trigger	I_{GT}	T_J = -40 °C	Anode supply = 6 V resistive load	270	mA
		T_J = 25 °C		150	
		T_J = 125 °C		80	
Maximum gate voltage that will not trigger	V_{GD}	T_J = 125 °C, rated V_{DRM} applied		0.25	V
Maximum gate current that will not trigger	I_{GD}	T_J = 125 °C, rated V_{DRM} applied		6	mA

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse and off-state leakage current at V_{RRM}, V_{DRM}	I_{RRM}, I_{DRM}	T_J = 130 °C, gate open circuit	20	mA
Maximum RMS insulation voltage	V_{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V
Maximum critical rate of rise of off-state voltage	dV/dt	T_J = 130 °C, linear to 0.67 V_{DRM}	1000	V/µs

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Junction operating temperature range	T_J		-40 to 130	°C
Storage temperature range	T_{Stg}			
Maximum internal thermal resistance, junction to case per leg	R_{thJC}	DC operation	0.22	°C/W
Typical thermal resistance, case to heatsink per module	R_{thCS}	Mounting surface flat, smooth and greased	0.1	
Mounting torque ± 10 % — to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	4	Nm
Mounting torque ± 10 % — busbar			3	
Approximate weight			75	g
			2.7	oz.
Case style		JEDEC®	AAP GEN VII (TO-240AA)	

ΔR CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSK.105..	0.04	0.048	0.063	0.085	0.125	0.033	0.052	0.067	0.088	0.127	°C/W

Note

- Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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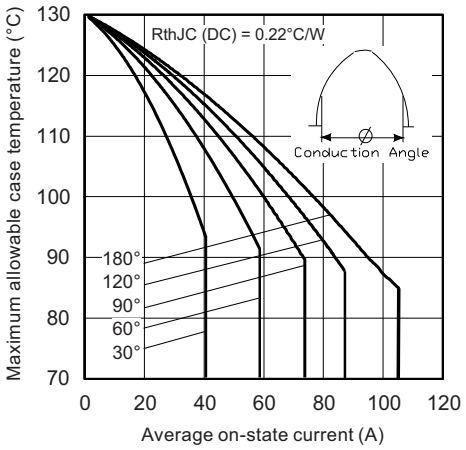

Fig. 1 - Current Ratings Characteristics

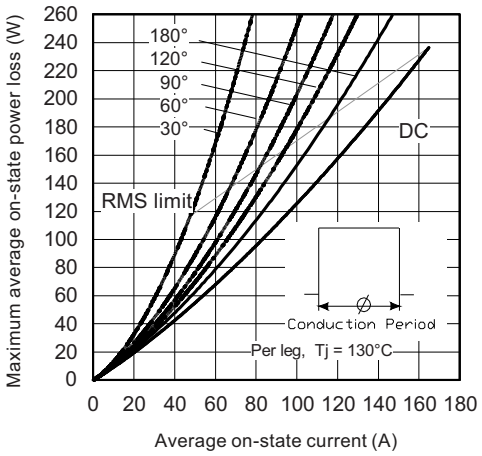

Fig. 4 - On-State Power Loss Characteristics

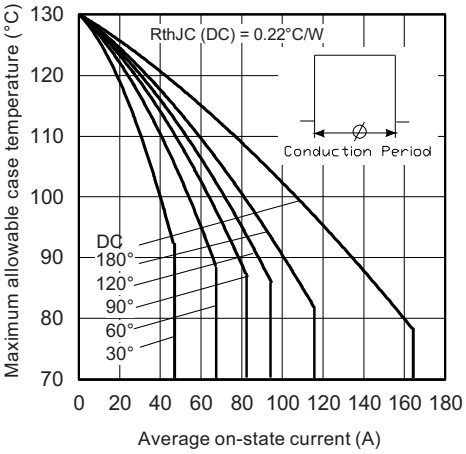

Fig. 2 - Current Ratings Characteristics

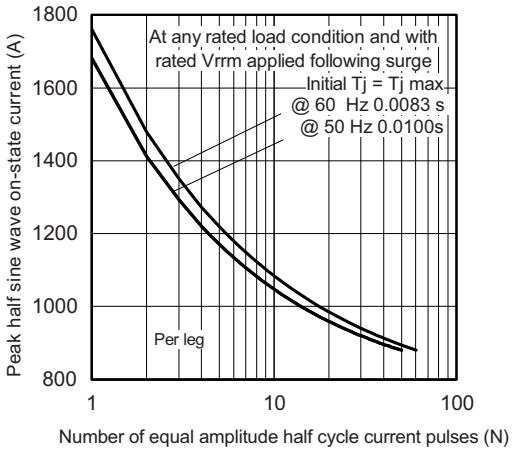

Fig. 5 - Maximum Non-Repetitive Surge Current

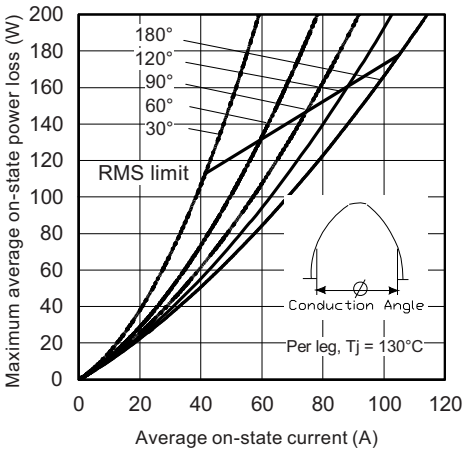

Fig. 3 - On-State Power Loss Characteristics

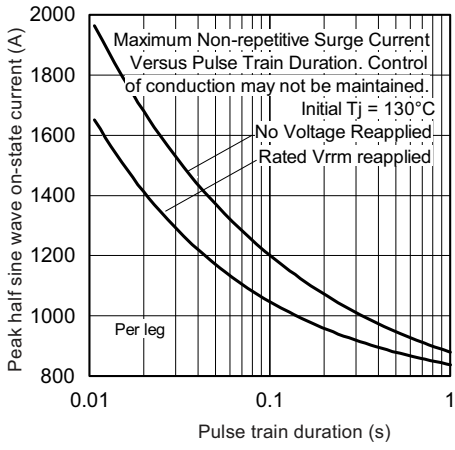

Fig. 6 - Maximum Non-Repetitive Surge Current

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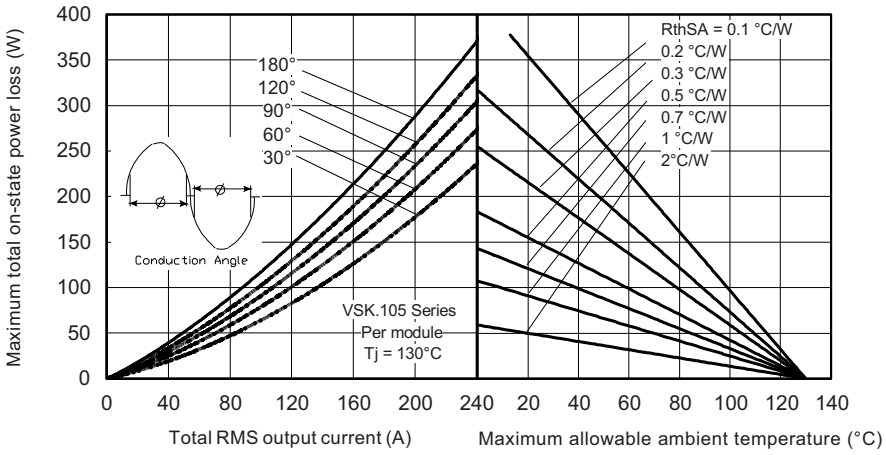

Fig. 7 - On-State Power Loss Characteristics

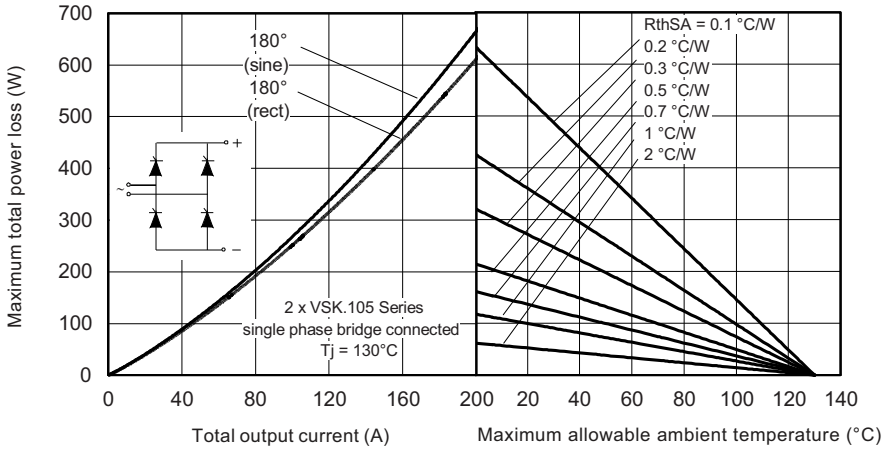

Fig. 8 - On-State Power Loss Characteristics

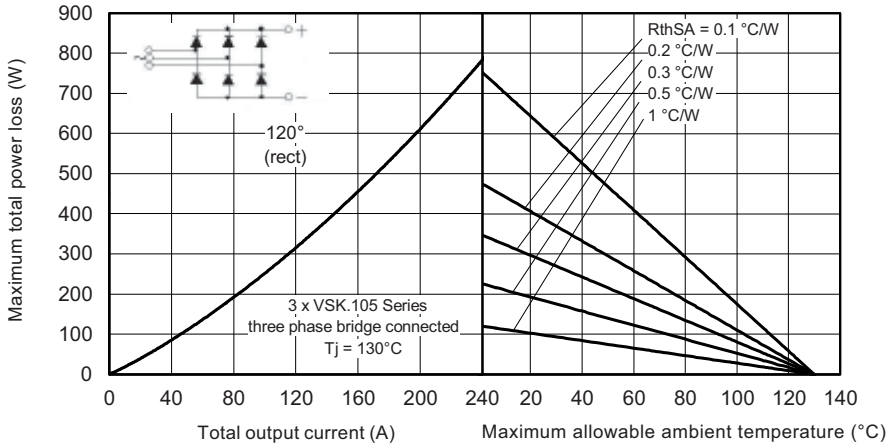

Fig. 9 - On-State Power Loss Characteristics

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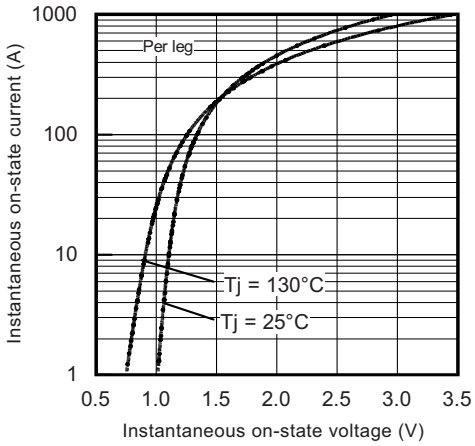

Fig. 10 - On-State Voltage Drop Characteristics

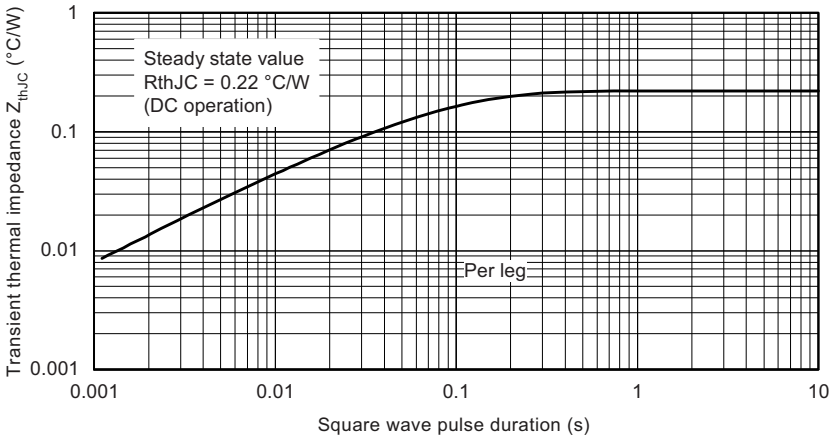

Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

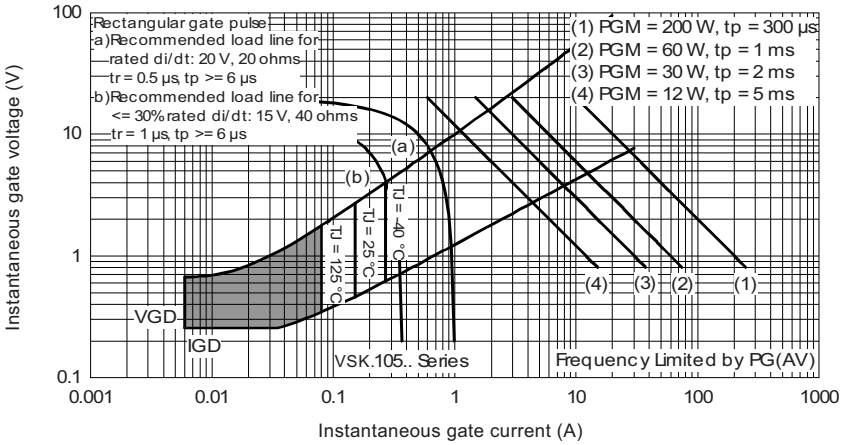

Fig. 12 - Gate Characteristics

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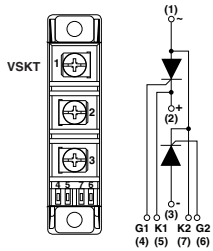
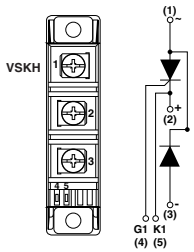
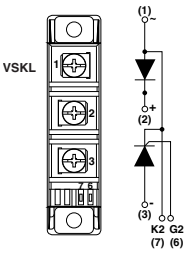
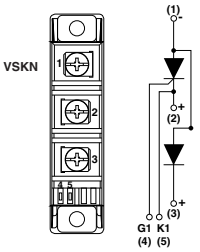
ORDERING INFORMATION TABLE

Device code	VS-VS	K	T	105	/	16
	1	2	3	4		5

1 - Vishay Semiconductors product
2 - Module type
3 - Circuit configuration (see Circuit Configuration table)
4 - Current code (105 A)
5 - Voltage code (see Voltage Ratings table)

Note
- To order the optional hardware go to www.vishay.com/doc?95172

CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	**CIRCUIT CONFIGURATION CODE**	**CIRCUIT DRAWING**
Two SCRs doubler circuit	T	
SCR/diode doubler circuit, positive control	H	
SCR/diode doubler circuit, negative control	L	
SCR/diode common anodes	N	

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95368

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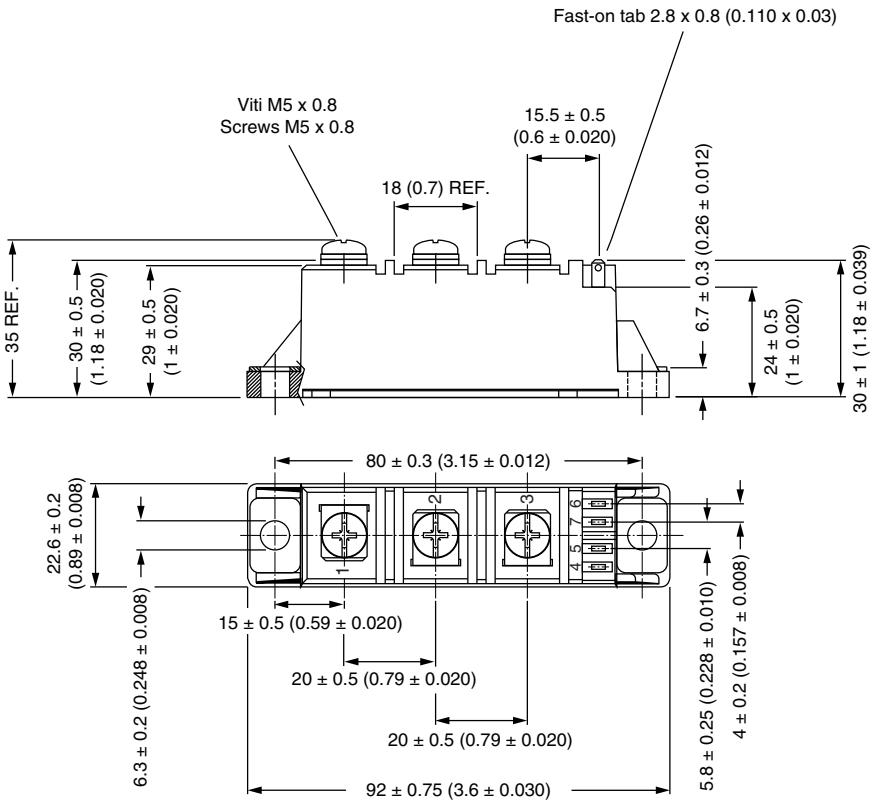
ADD-A-PAK Generation VII - Thyristor

DIMENSIONS in millimeters (inches)



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